Mohammadreza Shahzadeh

List of Publications by Year in descending order

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1307594 1372567 11 124 10 7 citations g-index h-index papers 11 11 11 126 docs citations times ranked citing authors all docs

#	Article	IF	CITATIONS
1	Nondiffusive Transport and Anisotropic Thermal Conductivity in High-Density Pt/Co Superlattices. ACS Applied Electronic Materials, 2021, 3, 1931-1936.	4.3	2
2	High-speed contactless sintering characterization for printed electronics by frequency-domain thermoreflectance. Flexible and Printed Electronics, 2020, 5, 035006.	2.7	3
3	Simultaneous measurement of anisotropic thermal conductivity and thermal boundary conductance of 2-dimensional materials. Journal of Applied Physics, 2019, 126, .	2.5	18
4	High-frequency measurements of thermophysical properties of thin films using a modified broad-band frequency domain thermoreflectance approach. Review of Scientific Instruments, 2018, 89, 084905.	1.3	5
5	Measuring the thermal properties of anisotropic materials using beam-offset frequency domain thermoreflectance. Journal of Applied Physics, 2018, 123, .	2.5	18
6	Measuring heat transport in electronic devices over small length scales. , 2017, , .		0
7	GaAs pyramidal quantum dot coupled to wetting layer in an AlGaAs matrix: A strain-free system. Physica E: Low-Dimensional Systems and Nanostructures, 2015, 68, 215-223.	2.7	13
8	Temperature Distribution in a Gaussian End-Pumped Nonlinear KTP Crystal: the Temperature Dependence of Thermal Conductivity and Radiation Boundary Condition. Brazilian Journal of Physics, 2015, 45, 1-9.	1.4	8
9	Electric field-induced nonlinearity enhancement in strained semi-spheroid-shaped quantum dots coupled to wetting layer. AIP Advances, 2014, 4, 127105.	1.3	15
10	Self-assembled strained pyramid-shaped InAs/GaAs quantum dots: The effects of wetting layer thickness on discrete and quasi-continuum levels. Physica E: Low-Dimensional Systems and Nanostructures, 2014, 61, 62-68.	2.7	29
11	Wetting layer-assisted modification of in-plane-polarized transitions in strain-free GaAs/AlGaAs quantum dots. Superlattices and Microstructures, 2014, 75, 514-522.	3.1	13